# NSN 5961-00-925-9119

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.375 inches

## **Overall Diameter:**

0.875 inches

# **Mounting Facility Quantity:**

2

#### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Germanium

## Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, collector-to-emitter, base open and 15.0

breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

3.00 amperes source cutoff current

#### Power Rating Per Characteristic:

62.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release3574 professional/industrial association specification

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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